

Description

The IRFR9024NTRPBF uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.



TO252-2L

General Features

 $V_{DS} = -60V I_{D} = -10 A$

 $R_{DS(ON)}$ < 120m Ω @ V_{GS} =10V

G S S

Application

Brushless motor

Load switch

Uninterruptible power supply

P-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)	
IRFR9024NTRPBF	TO252-2L	10P06 XXYY	2500	

Absolute Maximum Ratings (T_c=25^oCunless otherwise noted)

Symbol	Parameter Rating		Units	
Vos	Drain-Source Voltage -60		V	
Vgs	Gate-Source Voltage ±20		V	
I _D @T _C =25°C	Continuous Drain Current, V _{GS} @ -10V ¹	-10	А	
I _D @T _C =100°C	Continuous Drain Current, V _{GS} @ -10V ¹ -8.3		А	
I _D @T _A =25°C	Continuous Drain Current, V _{GS} @ -10V ¹	-3.3	А	
ID@Ta=70°C	Continuous Drain Current, V _{GS} @ -10V ¹	-2.7	А	
Ідм	Pulsed Drain Current ²	-26	А	
EAS	Single Pulse Avalanche Energy ³	29.8	mJ	
las	Avalanche Current	-24.4	A	
P _D @T _C =25°C	Total Power Dissipation ⁴	31.3	W	
P _D @T _A =25°C	Total Power Dissipation ⁴	2	W	
Тѕтс	Storage Temperature Range	-55 to 150	°C	
TJ	Operating Junction Temperature Range	-55 to 150	°C	
$R_{\theta JA}$	Thermal Resistance Junction-Ambient ¹ 62		°C/W	
R _θ JC	Thermal Resistance Junction-Case ¹	4.0	°C/W	

P-Channel Enhancement Mode MOSFET

P-Channel Electrical Characteristics (TJ =25 ℃, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
BVDSS	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =-250uA	-60			V	
∆BVDSS/∆TJ	BV _{DSS} Temperature Coefficient	Reference to 25°C , I _D =-1mA		-0.03		V/°C	
RDS(ON)	Static Drain-Source On-Resistance ²	V _{GS} =-10V , I _D =-3A		100	120	mΩ	
NDO(OIV)		V _{GS} =-4.5V , I _D =-2A		121	130		
VGS(th)	Gate Threshold Voltage	$V_{GS}=V_{DS}$, I_D =-250uA	-1.2	1.6	-2.5	V	
IDSS	Drain-Source Leakage Current	V _{DS} =-48V , V _{GS} =0V , T _J =25°C			1	uA	
1033		V _{DS} =-48V , V _{GS} =0V , T _J =55°C			5		
IGSS	Gate-Source Leakage Current	V_{GS} =±20 V , V_{DS} =0 V		1	±100	nA	
gfs	Forward Transconductance	V _{DS} =-5V , I _D =-3A		8.5		S	
Qg	Total Gate Charge (-4.5V)			12.1			
Qgs	Gate-Source Charge	V _{DS} =-48V , V _{GS} =-4.5V , I _D =-3A		2.2		nC	
Qgd	Gate-Drain Charge			6.3			
Td(on)	Turn-On Delay Time			9.2		- ns	
Tr	Rise Time	V _{DD} =-15V , V _{GS} =-10V , R _G =3.3□,		20.1			
Td(off)	Turn-Off Delay Time	I _D =-1A		46.7			
Tf	Fall Time			9.4			
Ciss	Input Capacitance			1137			
Coss	Output Capacitance	V _{DS} =-15V , V _{GS} =0V , f=1MHz		76		pF	
Crss	Reverse Transfer Capacitance			50			
IS	Continuous Source Current ^{1,5}	V _G =V _D =0V , Force Current			-13	Α	
VSD	Diode Forward Voltage ²	V _{GS} =0V , I _S =-1A , T _J =25°C			-1.2	V	

Note:

- 1. The data tested by surface mounted on a 1 inch 2 FR-4 board with 2OZ copper.
- $2\sqrt{100}$ The data tested by pulsed , pulse width ≤ 300 us , duty cycle $\leq 2\%$
- 3. The EAS data shows Max. rating . The test condition is V DD =-25V,V GS =-10V,L=0.1mH,IAS =-24A
- 4. The power dissipation is limited by 150 $\!\!\!^{\circ}\!\!\!^{\circ}$ junction temperature
- 5. The data is theoretically the same as I D and I DM, in real applications, should be limited by total power dissipation.



P-Channel Typical Characteristics

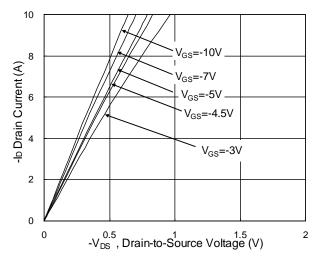


Fig.1 Typical Output Characteristics

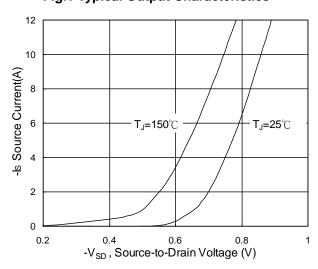


Fig.3 Forward Characteristics of Reverse

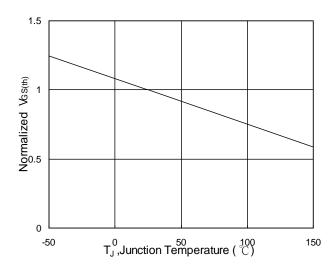


Fig.5 Normalized $V_{GS(th)}$ v.s T_J

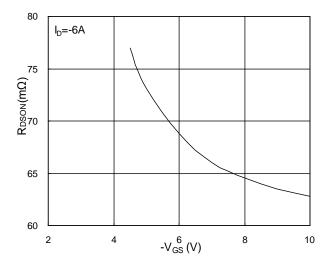


Fig.2 On-Resistance v.s Gate-Source

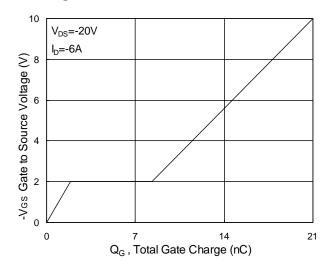


Fig.4 Gate-Charge Characteristics

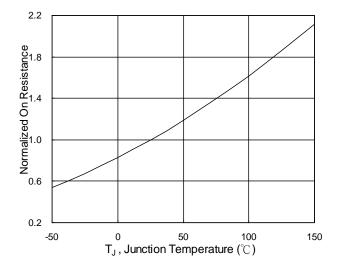
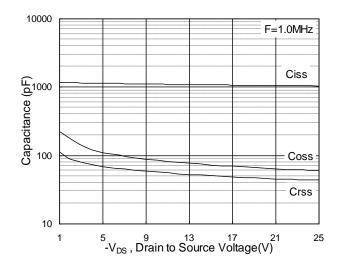


Fig.6 Normalized R_{DSON} v.s T_J



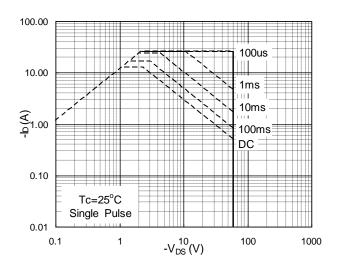


Fig.7 Capacitance

Fig.8 Safe Operating Area

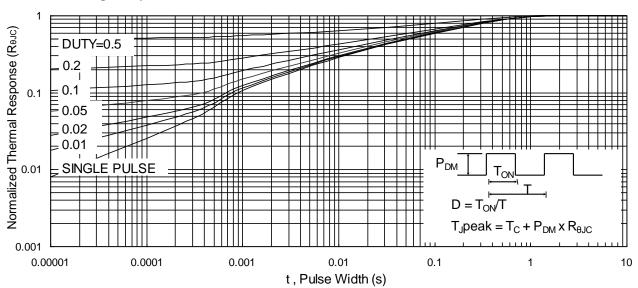


Fig.9 Normalized Maximum Transient Thermal Impedance

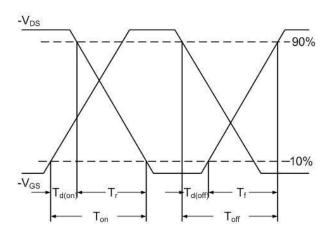


Fig.10 Switching Time Waveform

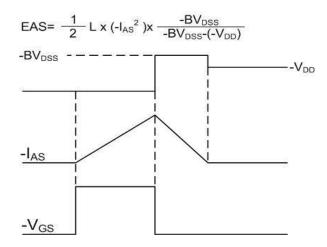
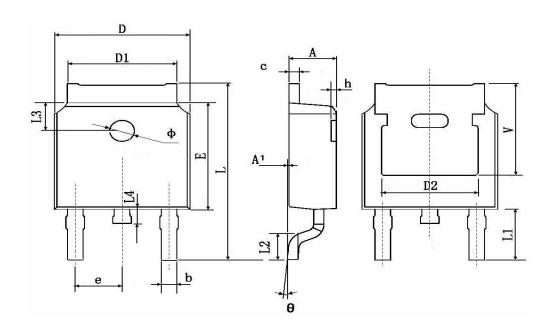


Fig.11 Unclamped Inductive Switching Waveform

P-Channel Enhancement Mode MOSFET

TO252-2L Package Information



Dimensions In Millimeters		Dimensions In Inches		
Min.	Max.	Min.	Max.	
2.200	2.400	0.087	0.094	
0.000	0.127	0.000	0.005	
0.660	0.860	0.026	0.034	
0.460	0.580	0.018	0.023	
6.500	6.700	0.256	0.264	
5.100	5.460	0.201	0.215	
4.830 TYP.		0.190 TYP.		
6.000	6.200	0.236	0.244	
2.186	2.386	0.086	0.094	
9.800	10.400	0.386	0.409	
2.900 TYP.		0.114 TYP.		
1 400	1 700	0.055	0.067	
	1.600 TYP. 0.063 TYP.			
0.600	1.000	0.024	0.039	
1.100	1.300	0.043	0.051	
0°	8°	0°	8°	
0.000	0.300	0.000	0.012	
5.350	TYP.	0.211 TYP.		
	Min. 2.200 0.000 0.660 0.460 6.500 5.100 4.830 6.000 2.186 9.800 2.900 1.400 1.600 0.600 1.100 0° 0.000	Min. Max. 2.200 2.400 0.000 0.127 0.660 0.860 0.460 0.580 6.500 6.700 5.100 5.460 4.830 TYP. 6.000 2.186 2.386 9.800 10.400 2.900 TYP. 1.700 1.600 TYP. 0.600 1.100 1.300 0° 8°	Min. Max. Min. 2.200 2.400 0.087 0.000 0.127 0.000 0.660 0.860 0.026 0.460 0.580 0.018 6.500 6.700 0.256 5.100 5.460 0.201 4.830 TYP. 0.190 6.000 6.200 0.236 2.186 2.386 0.086 9.800 10.400 0.386 2.900 TYP. 0.114 1.400 1.700 0.055 1.600 TYP. 0.063 0.600 1.000 0.024 1.100 1.300 0.043 0° 8° 0° 0.000 0.300 0.000	

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